

High Isolation, Silicon SP4T, Nonreflective Switch, 9 kHz to 12.0 GHz

Data Sheet

FEATURES

Nonreflective 50 Ω design Positive control range: 0 V to 3.3 V Low insertion loss: 0.8 dB at 8.0 GHz High isolation: 34 dB at 8.0 GHz High power handling 33 dBm through path 27 dBm termination path High linearity 1 dB compression (P1dB): 37 dBm typical Input third-order intercept (IIP3): 58 dBm typical at 8.0 GHz ESD rating: 4 kV human body model (HBM) 4 mm × 4 mm, 24-lead LFCSP package No low frequency spurious RF settling time (0.05 dB margin of final RFour): 9 µs

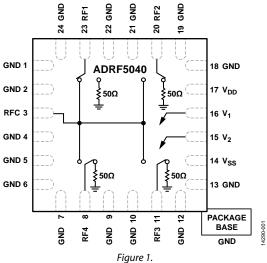
APPLICATIONS

Test instrumentation Microwave radios and very small aperture terminals (VSATs) Military radios, radars, and electronic counter measures (ECMs) Fiber optics and broadband telecommunications

GENERAL DESCRIPTION

The ADRF5040 is a general-purpose, broadband high isolation, nonreflective single-pole, quad-throw (SP4T) switch in an LFCSP surface-mount package. Covering the 9 kHz to 12.0 GHz range, the switch offers high isolation and low insertion loss. The switch features 34 dB isolation and 0.8 dB insertion loss up to

FUNCTIONAL BLOCK DIAGRAM



8.0 GHz, and a 9 μ s settling time of 0.05 dB margin of the final radio frequency output (RF_{OUT}). The switch operates using positive control voltage of 3.3 V and 0 V and requires +3.3 V and -3.3 V supplies. The ADRF5040 is packaged in a 4 mm \times 4 mm, surface-mount LFCSP package.

Rev. B

Document Feedback

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REVISION HISTORY

7/2017—Rev. A to Rev. B
Changes to Figure 2, Figure 3, and Figure 45
2/2017—Rev. 0 to Rev. A

2/201/—Rev. 0 to Rev. A	
Changes to Ordering Guide14	

7/2016—Revision 0: Initial Version

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SPECIFICATIONS

ELECTRICAL SPECIFICATIONS

 V_{DD} = 3.3 V, V_{SS} = –3.3 V, V_1 and V_2 = 0 V or V_{DD} , T_{A} = 25°C, 50 Ω system, unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	Тур	Max	Unit
INSERTION LOSS					
	9 kHz to 4.0 GHz		0.7		dB
	9 kHz to 8.0 GHz		0.8		dB
	9 kHz to 10.0 GHz		1.1		dB
	9 kHz to 12.0 GHz		2		dB
ISOLATION, RFC TO RF1 TO RF4 (WORST CASE)					
	9 kHz to 4.0 GHz		44		dB
	9 kHz to 8.0 GHz		34		dB
	9 kHz to 10.0 GHz		29.2		dB
	9 kHz to 12.0 GHz		20		dB
RETURN LOSS					
On State	9 kHz to 4.0 GHz		21		dB
	9 kHz to 8.0 GHz		19		dB
	9 kHz to 10.0 GHz		13.5		dB
	9 kHz to 12.0 GHz		8		dB
Off State	9 kHz to 4.0 GHz		25		dB
	9 kHz to 8.0 GHz		18.6		dB
	9 kHz to 10.0 GHz		15.5		dB
	9 kHz to 12.0 GHz		14.5		dB
RADIO FREQUENCY (RF) SETTLING TIME					
	50% V_1/V_2 to 0.05 dB margin of final RF _{OUT}		9		μs
	50% V_1/V_2 to 0.1 dB margin of final RF _{OUT}		7		μs
SWITCHING SPEED					
t _{RISE} /t _{FALL}	10% to 90% RF _{OUT}		1.3		μs
t _{on} /t _{off}	50% V ₁ /V ₂ to 90%/10% RF		3.5		μs
INPUT POWER	9 kHz to 12.0 GHz				
1 dB Compression (P1dB)			37		dBm
0.1 dB Compression (P0.1dB)			34		dBm
INPUT THIRD-ORDER INTERCEPT (IIP3)	Two-tone input power = 14 dBm at each tone		-		
	1 MHz to 2.0 GHz		62		dBm
	1 MHz to 8.0 GHz		58		dBm
	1 MHz to 12.0 GHz		53		dBm
RECOMMENDED OPERATING CONDITIONS					
Positive Supply Voltage (V _{DD})		3.0		3.6	v
Negative Supply Voltage (Vbb)		-3.6		-3.0	v
Control Voltage (V ₁ , V ₂) Range		0		V _{DD}	v
RF Input Power	$V_{DD} = 3.3 \text{ V}, V_{SS} = -3.3 \text{ V}, T_A = 85^{\circ}\text{C}, \text{ frequency} = 2 \text{ GHz}$			• 00	•
Through Path				33	dBm
Termination Path				27	dBm
Hot Switch Power Level	$V_{DD} = 3.3 \text{ V}, T_A = 85^{\circ}\text{C}, \text{ frequency} = 2 \text{ GHz}$			27	dBm
Case Temperature Range (T _{CASE})	$v_{00} = 5.5 v, TA = 05 C, Trequency = 2 GHZ$	-40		+85	°C
cuse remperature hange (TCASE)		-40		τ υ σ	

DIGITAL CONTROL VOLTAGE SPECIFICATIONS

 V_{DD} = 3.3 V \pm 10%, V_{SS} = –3.3 V \pm 10%, T_{CASE} = –40°C to +85°C, unless otherwise noted.

Table 2.

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition/Comments
INPUT CONTROL VOLTAGE (V1, V2)						<1 µA typical
Low	VIL	0		0.8	V	
High	VIH	1.4		$V_{\text{DD}} + 0.3$	V	

BIAS AND SUPPLY CURRENT SPECIFICATIONS

 $T_{CASE} = -40^{\circ}C$ to +85°C, unless otherwise noted.

Table 3.

Parameter	Symbol	Min	Тур	Мах	Unit	
SUPPLY CURRENT						
$V_{DD} = 3.3 V$	I _{DD}		20	100	μΑ	
$V_{SS} = -3.3 V$	I _{ss}		20	100	μΑ	

ABSOLUTE MAXIMUM RATINGS

Table 4.

Table 4.	
Parameter	Rating
Positive Supply Voltage (VDD) Range	–0.3 V to +3.7 V
Negative Supply Voltage (Vss) Range	-3.7 V to +0.3 V
Control Voltage (V1, V2) Range	-0.3 V to V_{DD} + 0.3 V
RF Input Power ¹ (V_{DD} , V_1 , $V_2 = 3.3$ V, $V_{SS} = -3.3$ V, $T_A = 85^{\circ}$ C, Frequency = 2 GHz)	
Through Path	34 dBm
Termination Path	28 dBm
Hot Switch Power Level ($V_{DD} = 3.3 V$, $T_A = 85^{\circ}C$, Frequency = 2 GHz)	30 dBm
Storage Temperature Range	–65°C to +150°C
Channel Temperature	135°C
Thermal Resistance (Channel to Package Bottom)	
Through Path	83°C/W
Terminated Path	100°C/W
MSL Rating	MSL3
ESD Sensitivity	
Human Body Model (HBM)	4 kV (Class 3)
Charged Device Model (CDM)	1.25 kV

¹ For the recommended operating conditions, see Table 1.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

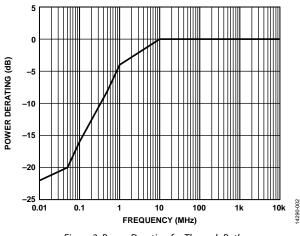


Figure 2. Power Derating for Through Path

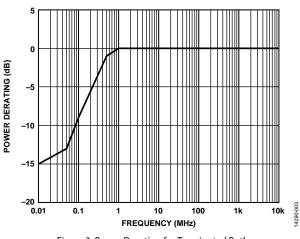


Figure 3. Power Derating for Terminated Path

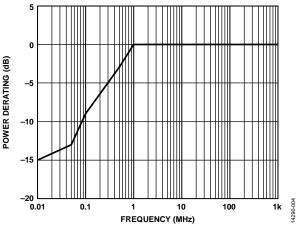


Figure 4. Power Derating for Hot Switching Power

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

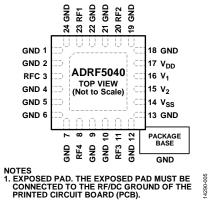


Figure 5. Pin Configuration

Table 5. Pin Function Descriptions

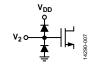
Pin No.	Mnemonic	Description
1, 2, 4 to 7, 9, 10, 12, 13, 18, 19, 21, 22, 24	GND	Ground. The package bottom has an exposed metal pad that must connect to the printed circuit board (PCB) RF/dc ground. See Figure 6 for the GND interface schematic.
3	RFC	RF Common Port. This pin is dc-coupled and matched to 50 Ω . A dc blocking capacitor is required if the RF line potential is not equal to 0 V dc.
8	RF4	RF4 Port. This pin is dc-coupled and matched to 50 Ω . A dc blocking capacitor is required if the RF line potential is not equal to 0 V dc.
11	RF3	RF3 Port. This pin is dc-coupled and matched to 50 Ω . A dc blocking capacitor is required if the RF line potential is not equal to 0 V dc.
14	Vss	Negative Supply Voltage Pin.
15	V ₂	Control Input Pin 2. See Table 2 and Table 6.
16	V ₁	Control Input Pin 1. See Table 2 and Table 6.
17	V _{DD}	Positive Supply Voltage.
20	RF2	RF2 Port. This pin is dc-coupled and matched to 50 Ω . A dc blocking capacitor is required if the RF line potential is not equal to 0 V dc.
23	RF1	RF1 Port. This pin is dc-coupled and matched to 50 Ω . A dc blocking capacitor is required if the RF line potential is not equal to 0 V dc.
	EPAD	Exposed Pad. The exposed pad must be connected to the RF/dc ground of the PCB.

Table 6. Truth Table

Digital Control Inputs			
V ₁	V ₂	Signal Path State	
Low	Low	RFC to RF1	
High	Low	RFC to RF2	
Low	High	RFC to RF3	
High	High	RFC to RF4	

INTERFACE SCHEMATICS





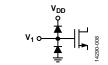
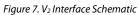


Figure 8. V₁ Interface Schematic



TYPICAL PERFORMANCE CHARACTERISTICS INSERTION LOSS, RETURN LOSS, AND ISOLATION

 V_{DD} = 3.3 V, V_{SS} = -3.3 V, T_{CASE} = 25°C, unless otherwise specified.

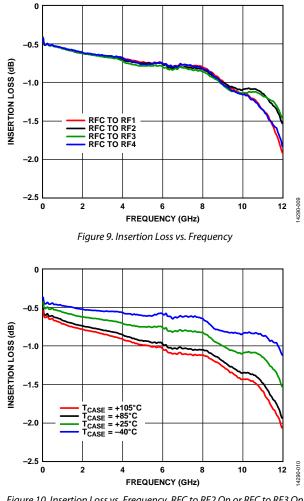
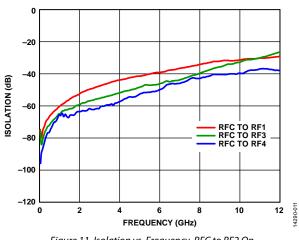


Figure 10. Insertion Loss vs. Frequency, RFC to RF2 On or RFC to RF3 On





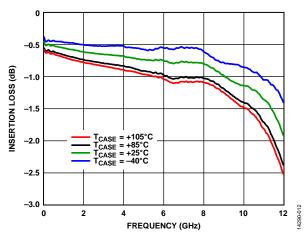


Figure 12. Insertion Loss vs. Frequency, RFC to RF1 On or RFC to RF4 On

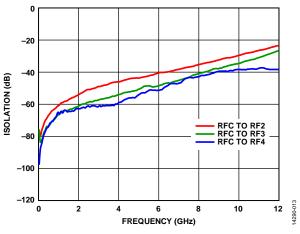


Figure 13. Isolation vs. Frequency, RFC to RF1 On

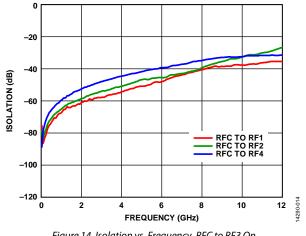
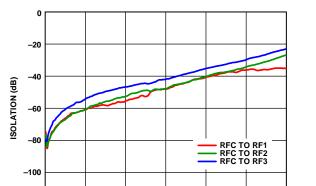


Figure 14. Isolation vs. Frequency, RFC to RF3 On

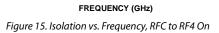
-120

0

2



 V_{DD} = 3.3 V, V_{SS} = –3.3 V, T_{CASE} = 25°C, unless otherwise specified.



6

8

10

4

14290-015

12

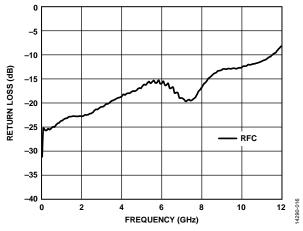


Figure 16. Return Loss vs. Frequency, RFC to RF4 On

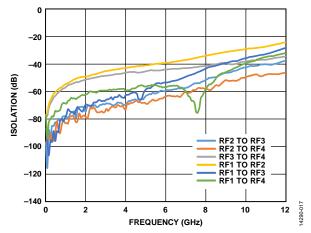


Figure 17. Channel to Channel Isolation vs. Frequency, RFC to RF1 On

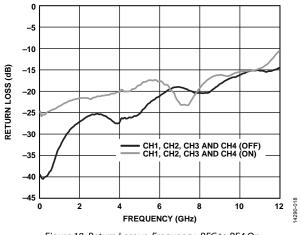


Figure 18. Return Loss vs. Frequency, RFC to RF4 On

INPUT POWER COMPRESSION AND INPUT THIRD-ORDER INTERCEPT

 V_{DD} = 3.3 V, V_{SS} = –3.3 V, T_{CASE} = 25°C, unless otherwise specified.

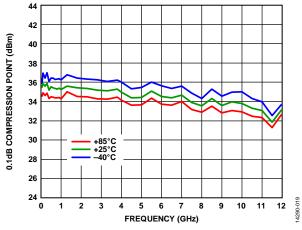


Figure 19. 0.1 dB Compression Point vs. Frequency over Temperature, V_{DD} = 3.3 V, V_{SS} = -3.3 V

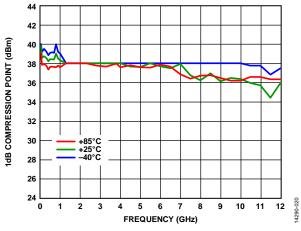


Figure 20. 1 dB Compression Point vs. Frequency over Temperature, $V_{DD} = 3.3 V$, $V_{SS} = -3.3 V$

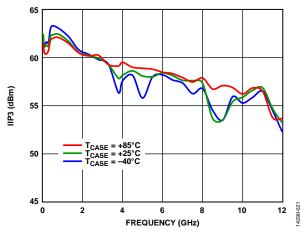


Figure 21. Input Third-Order Intercept (IIP3) vs. Frequency over Temperature, $V_{DD} = 3.3 V$, $V_{SS} = -3.3 V$

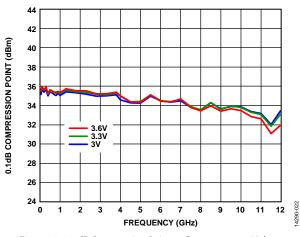


Figure 22. 0.1 dB Compression Point vs. Frequency over Voltage, $T_{CASE} = 25\,^{\circ}C$

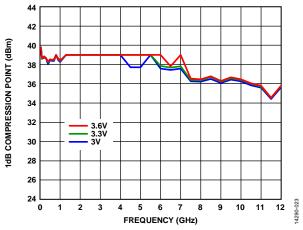


Figure 23. 1 dB Compression Point vs. Frequency over Voltage, $T_{CASE} = 25 \,^{\circ}\text{C}$

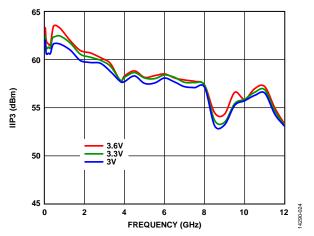
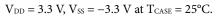
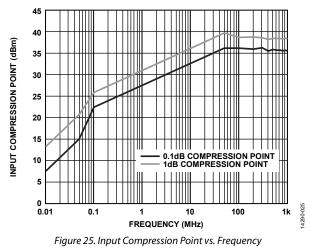
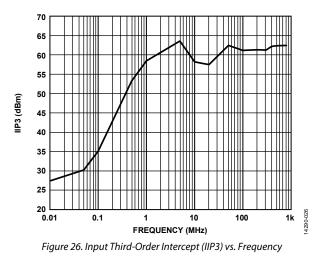


Figure 24. Input Third-Order Intercept (IIP3) vs. Frequency over Voltage, $T_{CASE} = 25^{\circ}C$

INPUT POWER COMPRESSION AND INPUT THIRD-ORDER INTERCEPT, 10 kHz TO 1 GHz $\,$







THEORY OF OPERATION

The ADRF5040 requires a positive supply voltage applied to the $V_{\rm DD}$ pin and a negative voltage supply applied to the $V_{\rm SS}$ pin. Bypassing capacitors are recommended on the supply lines to minimize RF coupling.

The ADRF5040 is controlled via two digital control voltages applied to the V_1 pin and the V_2 pin. A small value bypassing capacitor is recommended on these digital signal lines to improve the RF signal isolation.

The ADRF5040 is internally matched to 50 Ω at the RF input port (RFC) and the RF output ports (RF1, RF2, RF3, and RF4); therefore, no external matching components are required. The

RF1 through RF4 pins are dc-coupled, and dc blocking capacitors are required on the RF paths. The design is bidirectional; the input and outputs are interchangeable.

The ADRF5040 does not need any special power-up sequencing, and the relative order to power up the $V_{\rm DD}$ and $V_{\rm SS}$ supplies is not important. The V_1 and V_2 control signals can be applied only after $V_{\rm DD}$ is powered up; this sequence avoids forward biasing and causing damage to the internal ESD protection circuits. Turn on the RF signal after the device supply settles to a steady state.

APPLICATIONS INFORMATION Evaluation board

The ADRF5040-EVALZ evaluation board shown in Figure 27 is designed using proper RF circuit design techniques. Signal lines at the RF port have 50 Ω impedance, and the package ground

leads and backside ground slug must be connected directly to the ground plane. The evaluation board is available from Analog Devices, Inc. upon request.

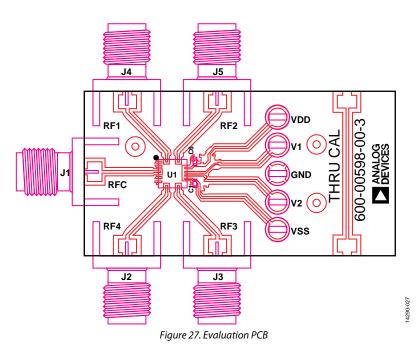
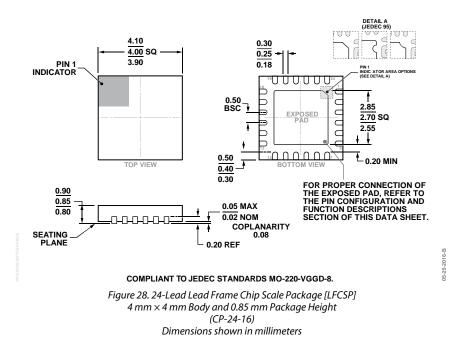


Table 7. Bill of Materials for the ADRF5040-EVALZ Evaluation Board

ltem	Description
J1 to J5	PC mount SMA RF connectors
TP1 to TP5	Through hole mount test points
C1, C6	100 pF capacitors, 0402 package
U1	ADRF5040 SP4T switch
PCB	600-00598-00-3 evaluation PCB, Rogers 4350 circuit board material

OUTLINE DIMENSIONS



ORDERING GUIDE

Model ¹	Temperature Range	MSL Rating ²	Package Description	Package Option	Branding ³
ADRF5040BCPZ	-40°C to +85°C	MSL3	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-16	ADRF
					5040
					#XXXXX
ADRF5040BCPZ-R7	-40°C to +85°C	MSL3	24-Lead Lead Frame Chip Scale Package [LFCSP]	CP-24-16	ADRF
					5040
					#XXXXX
ADRF5040-EVALZ			Evaluation Board		

¹ These models are RoHS Compliant Parts.

² See the Absolute Maximum Ratings section.

³ XXXXX is the 5-digit lot number.

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